

Zero bias anomaly in the density of states of low-dimensional metals

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Abstract. We consider the effect of Coulomb interactions on the average density of states (DOS) of disordered low-dimensional metals for temperatures T and frequencies ω smaller than the inverse elastic life-time $1/\tau_0$. Using the fact that long-range Coulomb interactions in two dimensions ($2d$) generate $\ln^2$ -singularities in the DOS $\nu(\omega)$ but only $\ln$ -singularities in the conductivity $\sigma(\omega)$, we can re-sum the most singular contributions to the average DOS via a simple gauge-transformation. If $\lim_{\omega \rightarrow 0} \sigma(\omega) > 0$, then a *metallic Coulomb gap* $\nu(\omega) \propto |\omega|/e^4$ appears in the DOS at $T = 0$ for frequencies below a certain crossover frequency Ω_2 which depends on the value of the DC conductivity $\sigma(0)$. Here, $-e$ is the charge of the electron. Naively adopting the same procedure to calculate the DOS in quasi $1d$ metals, we find $\nu(\omega) \propto (|\omega|/\Omega_1)^{1/2} \exp(-\Omega_1/|\omega|)$ at $T = 0$, where Ω_1 is some interaction-dependent frequency scale. However, we argue that in quasi $1d$ the above gauge-transformation method is on less firm grounds than in $2d$. We also discuss the behavior of the DOS at finite temperatures and give numerical results for the expected tunneling conductance that can be compared with experiments.

PACS. 71.10.Pm Fermions in reduced dimensions – 71.23.-k Electronic structure of disordered solids – 71.30.+h Metal-insulator transitions and other electronic transitions – 72.15.Rn Localization effects (Anderson or weak localization)

1 Introduction

In the early eighties, Altshuler and Aronov [1] perturbatively studied the effect of electron-electron interactions on the density of states (DOS) of low-dimensional weakly disordered interacting electronic systems. For temperatures T and frequencies ω smaller than the inverse elastic life-time $1/\tau_0$, they found that in reduced dimensions the interplay between disorder and electron-electron interactions gives rise to singular corrections to the averaged DOS. In two dimensions ($2d$), the long-range Coulomb interaction gives rise to a $\ln^2$ -correction to the average DOS [1],

$$\nu(\omega) \sim \nu_0 \left[1 - \frac{r_0}{4} \ln(|\omega|\tau_0) \ln(|\omega|\tau_1) \right], \quad 2d, \quad (1)$$

where

$$r_0 = \frac{1}{(2\pi)^2 \nu_0 D_0} = \frac{2e^2}{(2\pi)^2 \sigma_0} = \frac{1}{\pi k_F \ell} \quad (2)$$

is a dimensionless measure for the resistance of the system at frequency scale $\omega \approx \tau_0^{-1}$ (where σ_0 is the Drude conductivity), and the interaction-dependent time τ_1 is given by

$$\tau_1 = \frac{1}{D_0^2 \kappa^4 \tau_0} = \frac{4\tau_0}{(\kappa \ell)^4}. \quad (3)$$

Here, $\kappa = 2me^2$ is the Thomas-Fermi screening wave-vector in two dimensions, $\nu_0 = m/2\pi$ is the DOS at the

Fermi energy (per spin projection) of electrons with effective mass m and charge $-e$, $D_0 = v_F \ell/2$ is the diffusion coefficient in $2d$, and $\ell = v_F \tau_0$ is the elastic mean free path. We use units such that $\hbar = k_B = 1$. Note that for a good metal at high densities the Thomas-Fermi screening length is short compared with the elastic mean free path ($\kappa \ell \gg 1$) so that $\tau_1 \ll \tau_0$. In quasi $1d$ metallic wires (which consist of many transverse channels but permit diffusive motion only in one direction) the leading correction to the average DOS is [1]

$$\nu(\omega) \sim \nu_0 \left[1 - \sqrt{\frac{4\Omega_1}{\pi|\omega|}} \right], \quad \text{quasi } 1d, \quad (4)$$

where $\nu_0 = 1/(\pi v_F)$ is the DOS per spin in $1d$, and the frequency scale Ω_1 depends on the effective electron-electron interaction constant f_0 ,

$$\Omega_1 = \frac{f_0^2}{32\pi D_0}. \quad (5)$$

Here, $D_0 = v_F \ell$ is the (bare) diffusion coefficient in quasi $1d$.

Obviously, the correction terms in Eqs. (1) and (4) diverge for $\omega \rightarrow 0$, so that at low frequencies these perturbative expressions cease to be valid. What is the true low-frequency behavior of the DOS of disordered metals in

reduced dimensions? The answer to this question is relevant for a number of recent tunneling experiments [2, 3, 4], where a strong suppression of the tunneling conductance $G(V)$ as a function of the applied voltage has been observed (zero bias anomaly). The tunneling conductance is related to the DOS via $G(V) \propto \nu(\omega = eV)$, so that the experimentally observed zero bias anomaly in the tunneling conductance reflects the strong suppression of the average DOS at the Fermi energy.

In $2d$, the low-temperature behavior of the DOS of a strongly correlated disordered metal has recently been measured by Bielejec *et al.* [2]. While at higher temperatures they found a logarithmic correction, at the lowest temperatures they found a stronger-than linear suppression of the DOS, which has been interpreted in terms of a hard correlation gap. The knowledge of the low-energy behavior of the DOS of a $2d$ disordered metal with a finite conductivity might also be important to gain a better understanding of the physical mechanism that is responsible for the apparent metal-insulator transition in doped semiconductor devices [5, 6]. An intensely studied quasi $1d$ system where under certain conditions the electrons propagate diffusively in only one direction are multi-wall Carbon nanotubes [3, 4].

Let us briefly review previous calculations of the zero bias anomaly. In $2d$, the first attempt to determine the true low-frequency asymptotics of $\nu(\omega)$ was apparently due to Finkelstein [7] who found that $\nu(\omega) \propto |\omega|^{1/4}$ for $\omega \rightarrow 0$. However, in the derivation of this result he assumed that the conductivity $\sigma(\omega)$ diverges logarithmically for $\omega \rightarrow 0$. The behavior of the DOS of $2d$ disordered electrons with a finite conductivity was not calculated by Finkelstein. Later this problem was reconsidered by Belitz and Kirkpatrick [8], who found that for frequencies exceeding the crossover frequency

$$\Omega_2 \equiv \tau_0^{-1} \exp[-1/r_0], \quad (6)$$

the perturbative expression given in Eq. (1) can actually be exponentiated, so that

$$\nu(\omega) \approx \nu_0 \exp \left[-\frac{r_0}{4} \ln(|\omega|\tau_0) \ln(|\omega|\tau_1) \right]. \quad (7)$$

This expression has been re-derived in different ways by several authors [9, 10, 11]. Note, however, that Eq. (7) is not valid for frequencies smaller than the crossover frequency Ω_2 defined in Eq. (6) [8, 10, 11]. A simple interpolation formula for the DOS, which yields a physically sensible result even for $\omega \rightarrow 0$, has been proposed by one of us in Ref. [10]. This formula is based on a re-summation of the leading $\ln^2$ -singularities to all orders in perturbation theory, consistently neglecting sub-leading terms that involve only logarithmic corrections. In this approximation, one obtains

$$\nu(\omega) \approx \nu_0 \frac{2}{\pi} \int_{\tau_0}^{\infty} dt \frac{\sin(|\omega|t)}{t} \exp \left[-\frac{r_0}{4} \ln(t/\tau_0) \ln(t/\tau_1) \right]. \quad (8)$$

For $|\omega| \gtrsim \Omega_2 = \tau_0^{-1} \exp[-1/r_0]$, this expression reduces to Eq. (7). Note that Eq. (8) amounts to an exponentiation

of the perturbative result in the time domain, whereas in Eq. (7) the perturbation series is exponentiated in frequency space. In the limit $\omega \rightarrow 0$, the leading term in the asymptotic expansion of Eq. (8) is

$$\nu(\omega) \sim \nu_0 \frac{4}{\pi^{1/2}} \left(\frac{\tau_1}{\tau_0 r_0} \right)^{1/2} \frac{|\omega|}{\Omega_2}. \quad (9)$$

Noting that $\sqrt{\tau_0 \tau_1} = r_0/(\nu_0 e^4)$, Eq. (9) can also be written as

$$\nu(\omega) \sim C \frac{|\omega|}{e^4}, \quad (10)$$

where the numerical constant C is given by

$$C = 4(r_0/\pi)^{1/2} \exp[1/r_0]. \quad (11)$$

Surprisingly, Eq. (10) resembles the well-known classical Efros-Shklovskii Coulomb gap of two-dimensional electrons in the localized regime, where the DC conductivity $\sigma(0)$ vanishes [12]. Note, however, that in the derivation of Eq. (10) we have assumed that the DC conductivity $\sigma(0)$ remains finite, i.e. the electrons are assumed to be *delocalized*. The difference between the localized and the delocalized regime manifests itself in the dimensionless prefactor C : whereas in the case of the classical Coulomb gap of localized electrons the constant C is a number of the order of unity that depends on the geometry of the underlying lattice, for the quantum Coulomb gap discussed here, C depends on the dimensionless conductivity of the system. The existence of the Coulomb gap in the delocalized regime of a disordered interacting $2d$ metallic system was also found numerically by Efros and Pikus [13]. More recently, an intermediate delocalized phase in small clusters of disordered interacting electrons has been found numerically in Ref. [14].

In deriving Eq. (11), we have implicitly assumed that the DC conductivity $\sigma(0)$ does not deviate significantly from the conductivity $\sigma(\omega)$ at frequency $\omega \approx 1/\tau_0$. We have argued elsewhere [10] that a finite renormalization of the conductivity can be approximately taken into account by replacing $r_0 \rightarrow r_*$ in Eq. (11) where $r_* = e^2/(2\pi^2\sigma(0))$ corresponds to the true DC conductivity of the system. The connection between low-frequency behavior of the conductivity and the DOS has also been emphasized by Nazarov [15], and by Levitov and Shytov [9].

The zero bias anomaly in $1d$ has so far received much less attention than the corresponding anomaly in $2d$. Recent experiments on metallic Carbon nanotubes have motivated Mishchenko *et al.* [16] to study the fate of the perturbative Altshuler-Aronov correction in $1d$ at low frequencies. They found that long-range Coulomb interactions in a quasi $1d$ metal lead for $\omega \rightarrow 0$ to an exponentially small DOS,

$$\nu(\omega) \propto \exp \left[-\frac{\epsilon_0}{|\omega|} \ln \left(\frac{\epsilon_1}{|\omega|} \right) \right], \quad (12)$$

where ϵ_0 and ϵ_1 are some finite energy scales. We shall further comment on this result below. For frequencies exceeding a crossover scale $D_0/(2\pi R)^2$, where R is the radius

of the nanotube, Egger and Gogolin [17] found a crossover to two-dimensionality, which results in a power-law dependence of the DOS. However, below this crossover scale, 1d behavior is expected.

The rest of this work is organized as follows: In Sec. 2 we critically examine the non-perturbative method leading to the above results for the zero bias anomaly. In particular, we argue that only in the case of long-range Coulomb interactions in 2d the method can be formally justified; in particular, in quasi 1d the approximations leading to the result given in Eq. (12) are uncontrolled, so that we have serious doubts whether the exponential suppression of the DOS given in Eq. (12) is the physically correct low-frequency behavior in quasi 1d. In Sec. 3 we generalize the calculation of Ref. [10] to finite temperatures and present numerical results for the frequency-dependence of the average DOS which in principle can be compared with experimentally measured tunneling conductances. In Sec. 4 we discuss the DOS in quasi 1d and explain why in this case the calculation cannot be performed with the same confidence as in 2d. Finally, we end with a brief summary.

2 Summing the leading singularities via a gauge transformation

The average DOS of an interacting Fermi system at finite temperature $T = 1/\beta$ can be written in terms of the disorder-averaged Green function at coinciding space points $\mathcal{G}(\omega) \equiv \overline{\mathcal{G}(\mathbf{r}, \mathbf{r}, \omega)}$ as

$$\nu(\omega, T) = -\frac{1}{\pi} \coth\left(\frac{\beta\omega}{2}\right) \text{Im } \mathcal{G}(\omega). \quad (13)$$

To make contact with the disorder-averaged imaginary-time Green function at coinciding space points $G(\tau)$, we notice that due to particle-hole symmetry near the Fermi energy we have

$$\mathcal{G}(\omega) = -2 \int_0^\infty dt \sin \omega t G(\tau \rightarrow it + 0^+). \quad (14)$$

The problem of calculating the average DOS is now reduced to the problem of calculating the disorder-averaged imaginary-time Green function. An attempt to calculate $\nu(\omega)$ within perturbation theory fails at low frequencies because the perturbative expansion of $\nu(\omega)$ is plagued by singularities, see Eqs. (1) and (4). In 2d with long-range Coulomb interactions, these singularities diverge as $\ln^2 \omega$. At the same time, however, the perturbative expansion of the conductivity $\sigma(\omega)$ contains only less severe $\ln \omega$ -singularities [1, 7]. As a consequence, for sufficiently small frequencies, we may re-sum the most singular terms in the expansion of the average DOS *without considering simultaneously a similar re-summation for the average conductivity*, because we know a priori that $\ln^2$ -singularities do not appear in the calculation of $\sigma(\omega)$. In this sense, the problem of calculating the average DOS decouples from the problem of calculating the average conductivity. As

shown in Ref. [10], under these conditions we may sum the most singular contributions to the average DOS via a simple gauge transformation, which at finite temperature T leads to the following expression for the imaginary time Green function,

$$G(\tau) \approx G_0(\tau) e^{Q(\tau)}, \quad (15)$$

where $G_0(\tau)$ is the Green function of free fermions,

$$G_0(\tau) = -\nu_0 \frac{\pi/\beta}{\sin(\pi\tau/\beta)}, \quad (16)$$

and the Debye-Waller factor $Q(\tau)$ is given by [18]

$$Q(\tau) = -\frac{1}{\beta V} \sum_{\mathbf{q}, \omega_m} \frac{f_{\mathbf{q}, \omega_m}^{\text{RPA}}}{(D_0 \mathbf{q}^2 + |\omega_m|)^2} [1 - \cos(\omega_m \tau)]. \quad (17)$$

Here, $f_{\mathbf{q}, \omega_m}^{\text{RPA}}$ is the dynamically screened average Coulomb interaction, which is a function of momentum $\mathbf{q}$ and bosonic Matsubara frequency $\omega_m = 2\pi m/\beta$. The volume of the system is denoted by V . It is important to emphasize that in deriving Eqs. (15-17) the sub-leading logarithmic corrections have been ignored, so that it would be inconsistent to retain sub-leading terms involving only a single logarithm in the evaluation of the Debye-Waller factor.

Apparently, the above gauge-transformation method to re-sum the leading terms in the perturbative expansion of the single-particle Green function has first been used by Nazarov [15]. Later, several authors employed this technique to calculate the DOS of disordered interacting electrons [9, 10, 11]. However, one should keep in mind that in practice this method relies on the fact that the problem of calculating the average single-particle Green function decouples in the sense discussed above from the problem of calculating the conductivity. In particular, for 2d disordered electrons subject to *short-range interactions*, the perturbative calculation of $\nu(\omega)$ and $\sigma(\omega)$ both involve $\ln \omega$ -singularities, so that a naive application of the above gauge-transformation trick for short-range interactions in 2d is at least problematic. This is also the case for diffusive quasi 1d electrons, where the perturbative calculation of both $\nu(\omega)$ and $\sigma(\omega)$ leads to $|\omega|^{-1/2}$ -singularities [1]. Hence, also in this case it is problematic to calculate the average DOS using Eqs. (15-17) without considering simultaneously the low-frequency behavior of the conductivity. We shall come back to this point in Sec. 4.

3 Zero bias anomaly in 2d

In 2d the RPA-interaction is given by [1]

$$f_{\mathbf{q}, \omega_m}^{\text{RPA}} \approx (2D_0\nu_0)^{-1} |\omega_m|/\mathbf{q}^2. \quad (18)$$

This expression is valid in the frequency-momentum regime

$$|\omega_m|/D_0\kappa \ll |\mathbf{q}| \ll (|\omega_m|/D_0)^{1/2}, \quad |\omega_m| \ll \tau_0^{-1}, \quad (19)$$

which is responsible for the $\ln^2$ -corrections to the DOS. Converting the sum over Matsubara frequencies into an integral, the Debye-Waller factor (analytically continued to real time) may be written as

$$Q(it) = \frac{r_0}{2} \int_0^{\tau_0^{-1}} \frac{d\omega}{\omega} \ln \left(\frac{\omega}{D_0 \kappa^2} \right) \times \left[\frac{1 - \cos(\omega t)}{\tanh(\beta\omega/2)} + i \sin(\omega t) \right], \quad (20)$$

where we have taken the thermodynamic limit $V \rightarrow \infty$. To be consistent with the approximation made in Eq. (15), we retain only $\ln^2$ -singularities and ignore all terms involving only single logarithms: Within this approximation the imaginary part of $Q(it)$ vanishes, and for arbitrary temperatures we find $Q(it) \sim -\frac{r_0}{4} \ln(t/\tau_1) \ln(t/\tau_0)$. The DOS at finite temperature $T = 1/\beta$ is now given by

$$\nu(\omega, T) \approx \nu_0 \coth \left(\frac{\beta\omega}{2} \right) \frac{2}{\beta} \int_{\tau_0}^{\infty} dt \frac{\sin(\omega t)}{\sinh(\pi t/\beta)} \times \exp \left[-\frac{r_0}{4} \ln(t/\tau_1) \ln(t/\tau_0) \right]. \quad (21)$$

In the limit $T \rightarrow 0$ this equation reduces to Eq. (8). On the other hand, if we first take the limit $\omega \rightarrow 0$ and then consider the leading behavior at low temperatures, we obtain for $T \ll \Omega_2$

$$\nu(0, T) \sim 2C \frac{T}{e^4}, \quad (22)$$

where the numerical constant C is given in Eq. (11). Note that the prefactor in Eq. (22) is twice as large as the corresponding prefactor in Eq. (10). Thus, at low temperatures the average DOS at the Fermi energy vanishes linearly in T , which resembles the behavior of the average DOS in the localized regime. A plot of the DOS for various temperatures is shown in Fig. 1.

Formally, the derivation of Eq. (21) is only valid in the limit of weak disorder where $r_0 = 1/\pi k_F \ell \ll 1$. However, if the conductivity has a finite DC limit $\sigma(0)$, then it is reasonable to expect that the qualitative behavior of the DOS can be obtained by simply replacing $r_0 \rightarrow r_* = (e^2/h)/\pi\sigma(0)$ in Eq. (21). In Ref. [10] this replacement has been justified via a simple renormalization group argument. For a possible comparison of our results with future tunneling experiments on semiconductor materials which apparently show a metal-insulator transition [5,6] (as far as we know, such experiments have not been performed yet), we have plotted in Fig. 1 the frequency-dependence predicted by Eq. (21) for $r_0 \rightarrow r_* = 1/\pi$, corresponding to the zero-temperature conductivity of order $\sigma(0) \approx e^2/h$. Saturation values in this regime are typically encountered in the metallic regime close to the apparent metal-insulator transition [6]. The temperature-dependence of the average DOS at the Fermi energy is shown in Fig. 2.

It should be noted that in deriving Eq. (21) we have consistently neglected corrections involving single logarithms. We cannot exclude the possibility that these corrections lead to a further depletion of the Coulomb gap.

For example, taking the (sub-leading) imaginary part of the full Debye-Waller factor given in Eq. (20) into account would lead to a nonlinear suppression of the DOS. However, as discussed above, such an approximation would not be systematic.

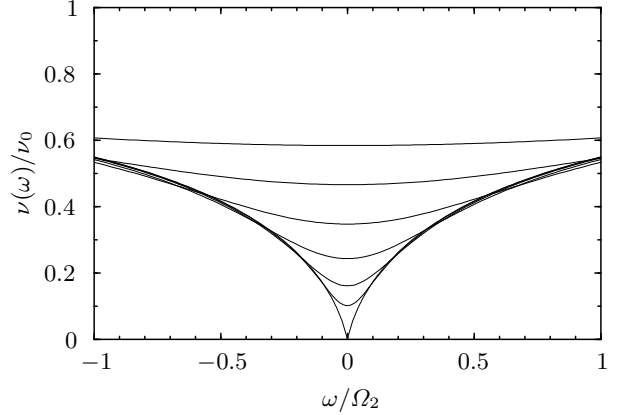


Fig. 1. Graph of the average DOS $\nu(\omega)$ in 2d for various temperatures, see Eq. (21). We have chosen $r_0 \rightarrow r_* = 1/\pi$ and $\tau_1 = \tau_0$. Curves from top to bottom are for $T/\Omega_2 = 0.8, 0.4, 0.2, 0.1, 0.05, 0.025, 0$.

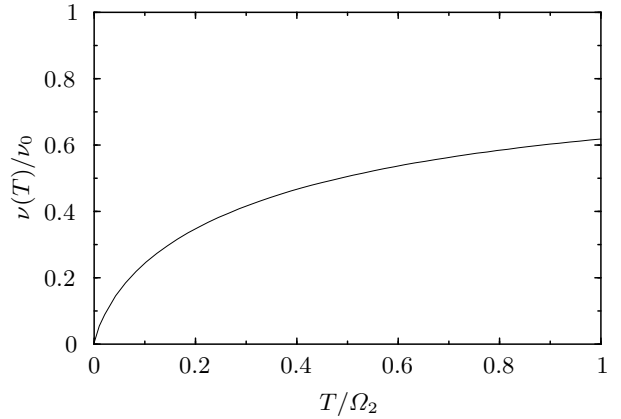


Fig. 2. Temperature-dependence of the average DOS $\nu(T)$ at the Fermi energy in 2d. The parameters are again $r_0 \rightarrow r_* = 1/\pi$ and $\tau_1 = \tau_0$.

4 Zero bias anomaly in 1d

As discussed in Sec. 2, the naive application of Eqs. (15-17) in quasi 1d is problematic, because in this case the interaction corrections to the DOS and to the conductivity both involve the same type of singularities. Keeping this caveat in mind, let us nevertheless briefly discuss the

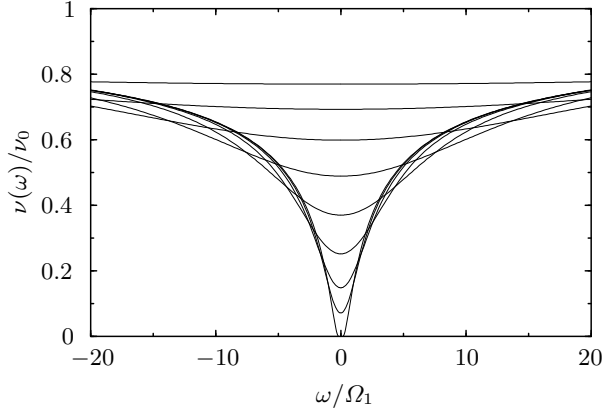


Fig. 3. Graph of the average DOS $\nu(\omega)$ in 1d for various temperatures, see Eq. (24). The curves from top to bottom are for $T/\Omega_1 = 32, 16, 8, 4, 2, 1, 0.5, 0.25, 0$.

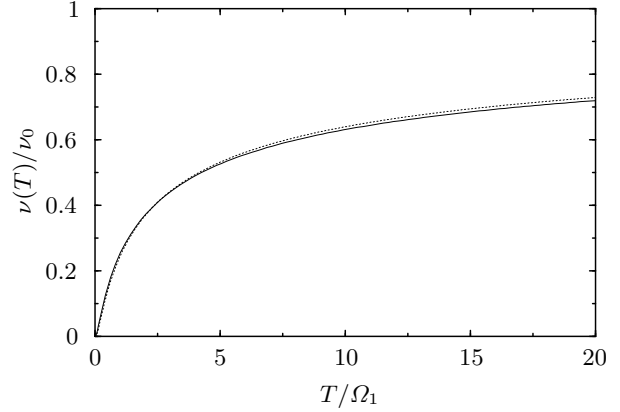


Fig. 4. Solid line: graph of the average DOS $\nu(T)$ for $\omega = 0$, see Eq. (24). Dotted dotted line: the approximation $\exp(-\sqrt{2\Omega_1/T})$.

predictions of Eqs. (15-17) in quasi 1d. A similar calculation has recently been performed in Ref. [16].

Since screening is much less effective in one dimension than in higher dimensions, we simply approximate the one-dimensional RPA-interaction by a constant, $f_{q,\omega_m}^{\text{RPA}} \approx f_0$ [1]. This approximation should be correct up to logarithmic corrections in frequency. A calculation analogous to the one leading to Eq. (20) results in

$$Q(it) = -\sqrt{2\Omega_1} \left[\int_0^\infty \frac{d\omega}{\sqrt{2\pi}} \frac{1 - \cos(\omega t)}{\omega^{3/2} \tanh(\beta\omega/2)} + i\sqrt{t} \right], \quad (23)$$

where Ω_1 is given in Eq. (5). Note that in 1d, there is no need for an ultraviolet cutoff. At $T = 0$, we have $\text{Re } Q(it) = \text{Im } Q(it)$, such that the imaginary part of $Q(it)$ cannot be neglected. The DOS at finite temperature $T = 1/\beta$ can now be written as

$$\nu(\omega, T) \approx \nu_0 \coth\left(\frac{\beta\omega}{2}\right) \frac{2}{\beta} \int_0^\infty dt \frac{\sin(\omega t) \cos(\sqrt{2\Omega_1}t)}{\sinh(\pi t/\beta)} \times \exp\left[-\sqrt{\frac{\Omega_1}{\pi}} \int_0^\infty d\omega' \frac{1 - \cos(\omega't)}{(\omega')^{3/2} \tanh(\beta\omega'/2)}\right]. \quad (24)$$

As can be easily checked, for $|\omega| \gg \max\{\Omega_1, T\}$, Eq. (24) reduces to the perturbative result given in Eq. (4). A graph of $\nu(\omega, T)$ for different temperatures is shown in Fig. 3. The DOS at the Fermi energy as a function of temperature is shown in Fig. 4. The DOS is well approximated by $\nu(T) \approx \nu_0 \exp(-\sqrt{2\Omega_1/T})$ which is quite similar to a result found in Ref. [16]. At zero temperature, Eq. (24) may be simplified to

$$\nu(\omega, T = 0) = \frac{\nu_0}{\pi} \text{Re} \int_0^\infty dx \frac{\sin x^2}{x} \exp\left[-2x\sqrt{\frac{i\Omega_1}{|\omega|}}\right]. \quad (25)$$

For $|\omega| \ll \Omega_1$, this integral is easily evaluated within a saddle-point approximation,

$$\nu(\omega, T = 0) \sim \nu_0 \sqrt{\frac{|\omega|}{\pi\Omega_1}} \exp\left[-\frac{\Omega_1}{|\omega|}\right], \quad |\omega| \ll \Omega_1, \quad (26)$$

which differs from the corresponding expression given by Mishchenko *et al.* [16] (see Eq. (12)) by a different prefactor. The exponential suppression of the DOS is quite surprising and is possibly an artifact of the inconsistent exponentiation of the $|\omega|^{-1/2}$ -singularities inherent in Eqs. (26) and (12) for quasi 1d systems. Recall that for long-range Coulomb interactions in 2d it is possible to separate $\ln^2$ -terms from sub-leading terms already neglected in the approximation made in Eq. (15). In 1d, a similar separation is not possible. The ultimate low-frequency behavior of the DOS in 1d might therefore be altered by diagrams neglected in Eq. (15).

5 Summary and conclusions

In summary, we have considered the fate of the singular perturbative corrections to the average DOS in quasi 1d and 2d disordered metals when the frequency and the temperature are reduced such that one leaves the perturbative regime. For a 2d metal with long-range Coulomb interactions, it is possible to re-sum the leading $\ln^2$ -singularities in the perturbative expansion of the average DOS to all orders in perturbation theory. The method relies on the fact that similar singularities do not appear in the perturbative expansion of the average conductivity. For a 2d system with short-range interactions or for a quasi 1d system a similar separation of energy scales does not exist, so that approximate expressions of the type given in Eq. (15), which involve the exponentiation of a certain subclass of Feynman diagrams, are problematic in this case. Thus, in practice the gauge-transformation trick described above, which has recently been employed by many authors [9,

10,11,15], is only controlled in the case of $2d$ disordered electrons interacting with *long-range* Coulomb forces in the regime where the conductivity has a finite DC-limit. In this case this method yields a simple interpolation formula (21) for the average DOS, which predicts a smooth crossover from the perturbative regime at high frequencies to a new low-frequency regime, where $\nu(\omega, T)$ vanishes linearly in ω or T . The average DOS of *localized* classical electrons is known to show a similar frequency- or temperature-dependence [12]. In contrast, the metallic Coulomb gap discussed here has a quantum mechanical origin and requires delocalized electrons with a finite DC conductivity. Numerical evidence for such a metallic Coulomb gap has been found in Ref. [13].

In principle, it should be possible to verify the existence of the metallic Coulomb gap experimentally via tunneling experiments in strongly correlated disordered systems with a finite DC conductivity. The expected shape of a typical trace of the tunneling conductance as a function of the applied voltage is shown in Fig. 1. Recent tunneling experiments by Bielejec *et al.* [2] in quench-condensed Beryllium films show a crossover from the perturbative regime with logarithmic corrections to an apparently linear Coulomb gap in the DOS. However, at the lowest temperatures the DOS exhibits a hard correlation gap, the origin of which remains open.

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18. Actually, in Ref. [10] the factor $D_0 \mathbf{q}^2$ in the denominator of Eq. (17) does not explicitly appear; instead, the frequency-summation is restricted to the regime $|\omega_m|/D_0 \kappa \ll |\mathbf{q}| \ll (|\omega_m|/D_0)^{1/2}$. Both prescriptions lead to identical results as far as the summation of the leading $\ln^2$ -singularities are concerned. Here we implement the cutoff as in Eq. (17), because then Eqs. (15) and (17) are identical with the result obtained by Kamenev and Andreev within a field theoretic approach based on the Keldysh formalism [11].